

Ultra-low power digital PDM XENSIV™ MEMS microphone

Features

- Low current consumption in high performance mode (540µA)
- Ultra-low current consumption in low power mode (170µA)
- Signal to noise ratio (SNR) of 67dB(A)
- Acoustic overload point at 128dB SPL
- Flat frequency response with ultra low frequency roll-off at 10Hz
- Component level IP57 dust and water resistant
- Package dimensions: 3mm x 2mm x 0.98mm
- Enhanced RF shielding
- Digital PDM output
- Bottom port

Potential applications

- Active Noise Cancellation (ANC) headphones and earbuds
- High quality audio capturing
 - Laptops and tablets
 - Conference systems
 - Cameras, camcorders, and camera accessories
- Devices with Voice User Interface (VUI)
 - Smart speakers
 - Home automation
 - IOT devices
- Industrial or home monitoring with audio pattern detection



Product validation

Technology qualified for industrial applications.

Ready for validation in industrial applications according to the relevant tests of IEC 60747 and 60749 or alternatively JEDEC47/20/22.

Description

Discover the IM67D128BV01 – an ultra-low power digital XENSIV™ MEMS microphone, designed for applications which require long battery life and environmental robustness in an exceptionally small package.

With a Signal-to-noise ratio (SNR) of 67dB(A) and low corner frequency of 10Hz the microphone enables a clear audio experience without compromising on battery life.

Enabled by a revolutionary digital microphone ASIC, the IM67D128BV01 balances performance in a very small package with low current consumption of 540µA.

Type	Package	Marking	Ordering code
IM67D128BV01	PG-TLGA-5-8	I67D30	SP006037658

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1 Block diagram

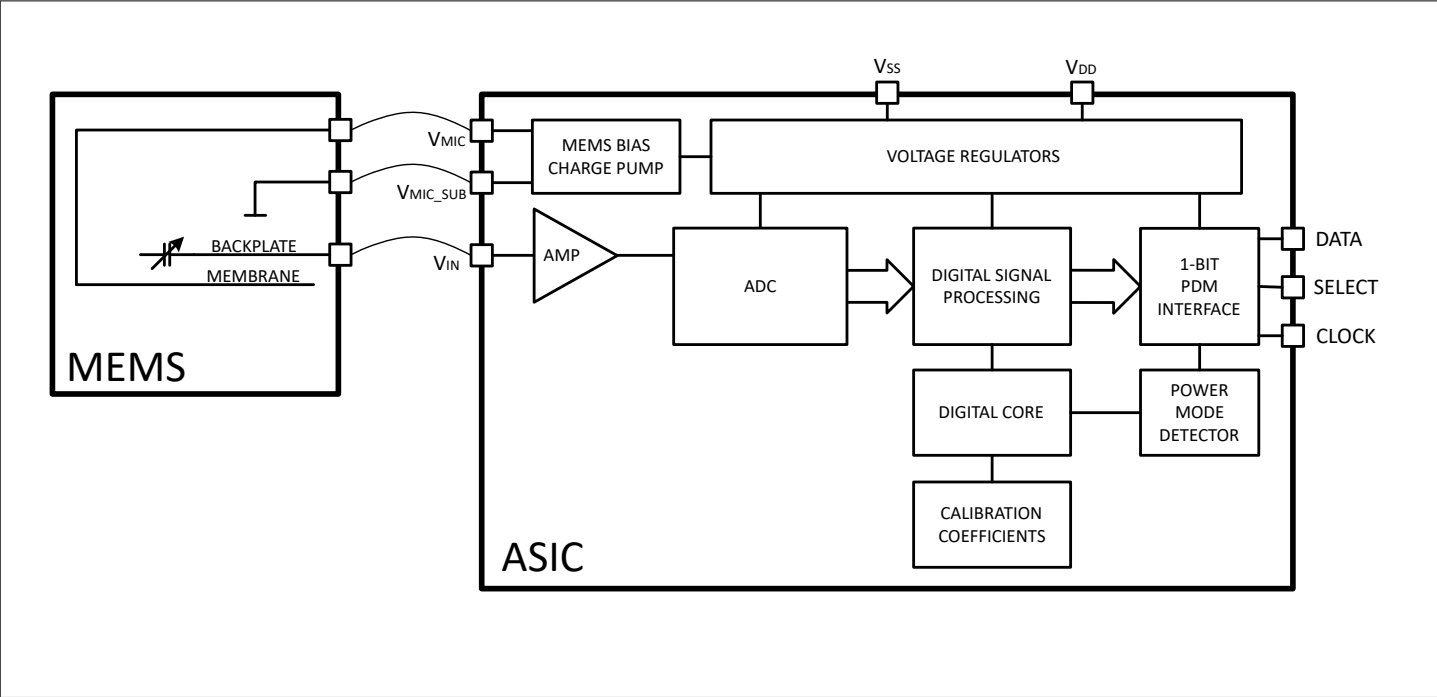


Figure 1 Block diagram

2 Typical performance characteristics

Test conditions: $V_{DD}=1.8V$, $f_{CLK}=3.072MHz$, $T_A=25^{\circ}C$, unless otherwise specified.

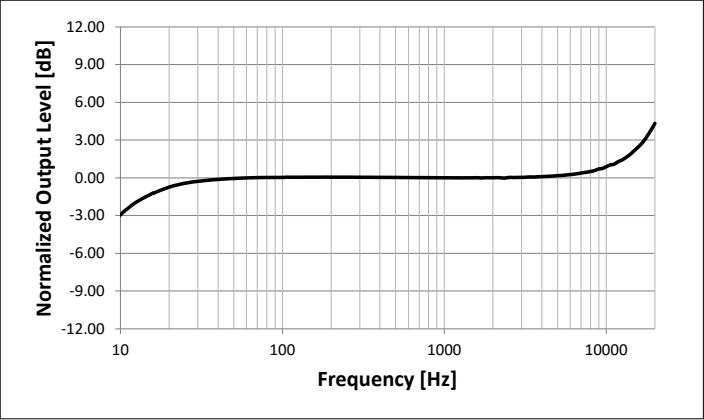


Figure 2 Typical amplitude response

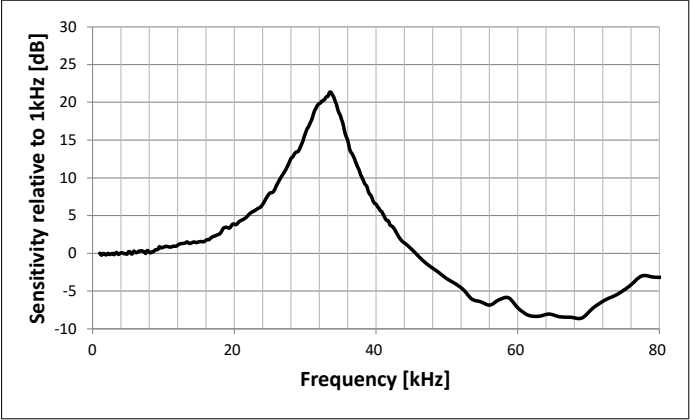


Figure 3 Typical ultrasonic response

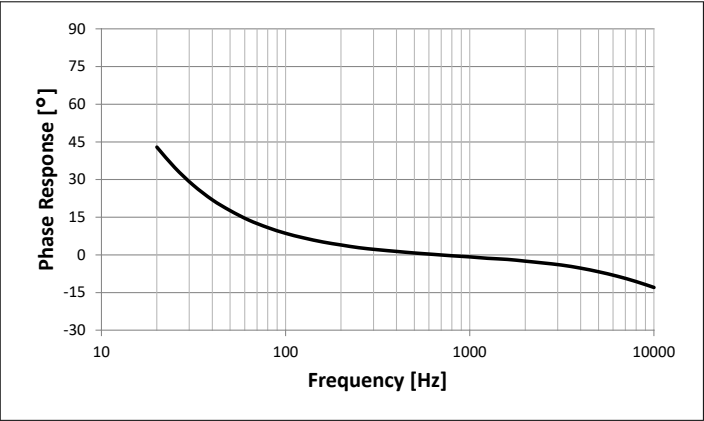


Figure 4 Typical phase response

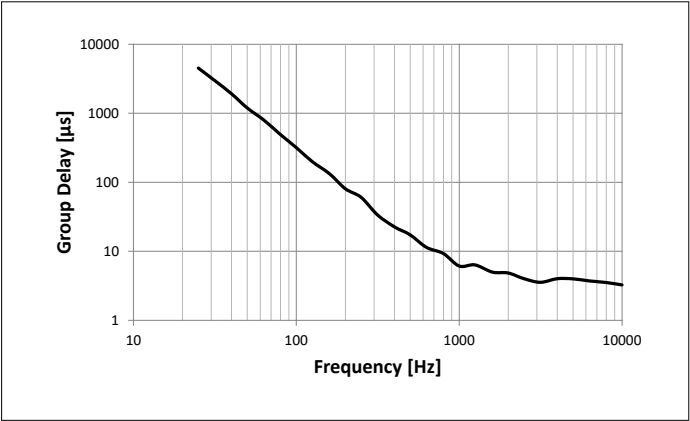


Figure 5 Typical group delay

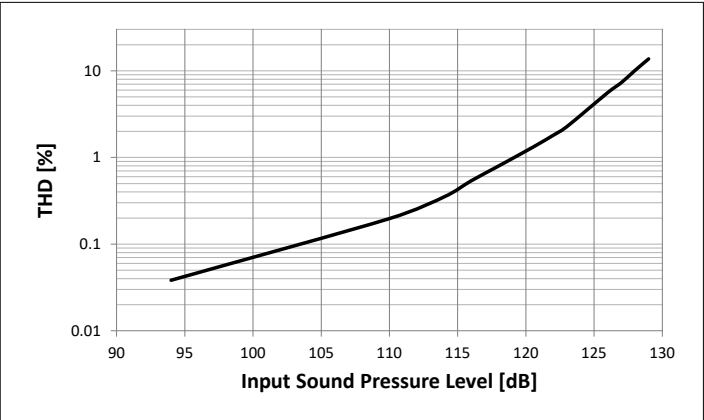


Figure 6 Typical THD vs SPL

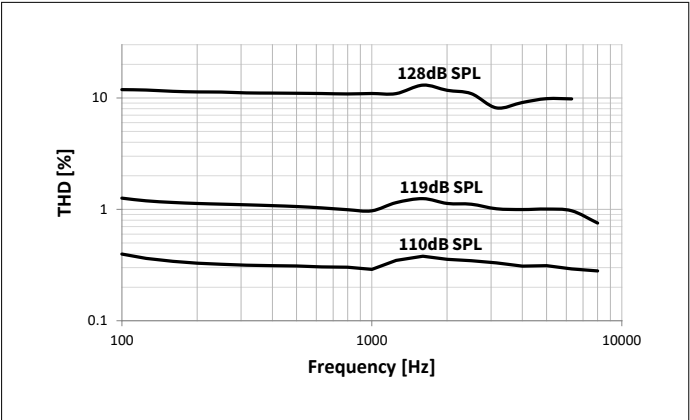


Figure 7 Typical THD vs frequency

2 Typical performance characteristics

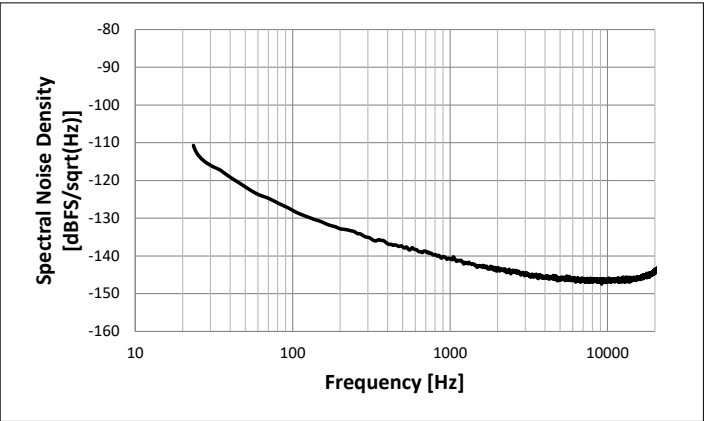


Figure 8 Typical noise floor power spectral density (unweighted)

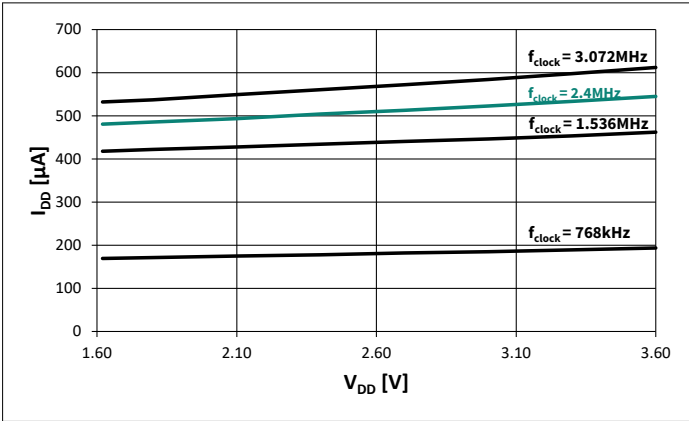


Figure 9 Typical I_{DD} vs V_{DD}

3 Acoustic characteristics

Table 1 Acoustic specifications normal mode

Test conditions (unless otherwise specified in the table): $V_{DD} = 1.8V$, $f_{CLK} = 3.072MHz$, $OSR=64$, $T_A = 25^{\circ}C$, 55% R.H., audio bandwidth 20Hz to 20kHz, select pin grounded, no load on DATA, $T_{edge} = 9ns$

Parameter		Symbol	Values			Unit	Note or Test Condition
			Min.	Typ.	Max.		
Sensitivity		S	-38	-37	-36	dBFS	1kHz, 94 dB SPL
Low Frequency Roll-off		LFRO		10		Hz	-3dB relative to 1kHz
Resonant Frequency Peak				33		kHz	
Signal to Noise Ratio	F _{clock} = 1.536MHz	SNR		66		dB(A)	20Hz to 20kHz bandwidth, A-Weighted
	F _{clock} = 2.0MHz			66.5			
	F _{clock} = 2.4MHz			66.5			
	F _{clock} = 3.072MHz			67			
Total Harmonic Distortion	94dB SPL	THD			0.3	%	Measuring 2nd to 5th harmonics; 1kHz. S=typ
	119dB SPL			1.0			
	128dB SPL			10.0			
Acoustic Overload Point	10% THD	AOP		128		dB SPL	Measuring 2nd to 5th harmonics; 1kHz. S=typ
Group Delay	100Hz			320		µs	
	1kHz			6			
	4kHz			4			
Phase Response	100Hz			9		°	
	1kHz			-0.8			
	4kHz			-5			
Directivity			Omnidirectional				
Polarity		Positive pressure increases density of 1's, negative pressure decreases density of 1's in data output					

Table 2 **Acoustic specifications low power mode**

Test conditions (unless otherwise specified in the table): $V_{DD} = 1.8V$, $f_{CLK} = 768kHz$, $OSR=48$, $T_A = 25^{\circ}C$, 55% R.H., audio bandwidth 20Hz to 8kHz, select pin grounded, no load on DATA, $T_{edge} = 9ns$

Parameter		Symbol	Values			Unit	Note or Test Condition
			Min.	Typ.	Max.		
Sensitivity		S	-28	-27	-26	dBFS	1kHz, 94 dBSPL
Signal to Noise Ratio	$F_{clock} = 768kHz$	SNR		66		dB(A)	20Hz to 8kHz bandwidth, A-Weighted
Total Harmonic Distortion	94dBSPL	THD			0.3	%	Measuring 2nd to 5th harmonics; 1kHz. S=typ
	119dBSPL			1.0			
	123dBSPL			10.0			
Acoustic Overload Point	10% THD	AOP		123		dB SPL	Measuring 2nd to 5th harmonics; 1kHz. S=typ

4 Free field frequency response

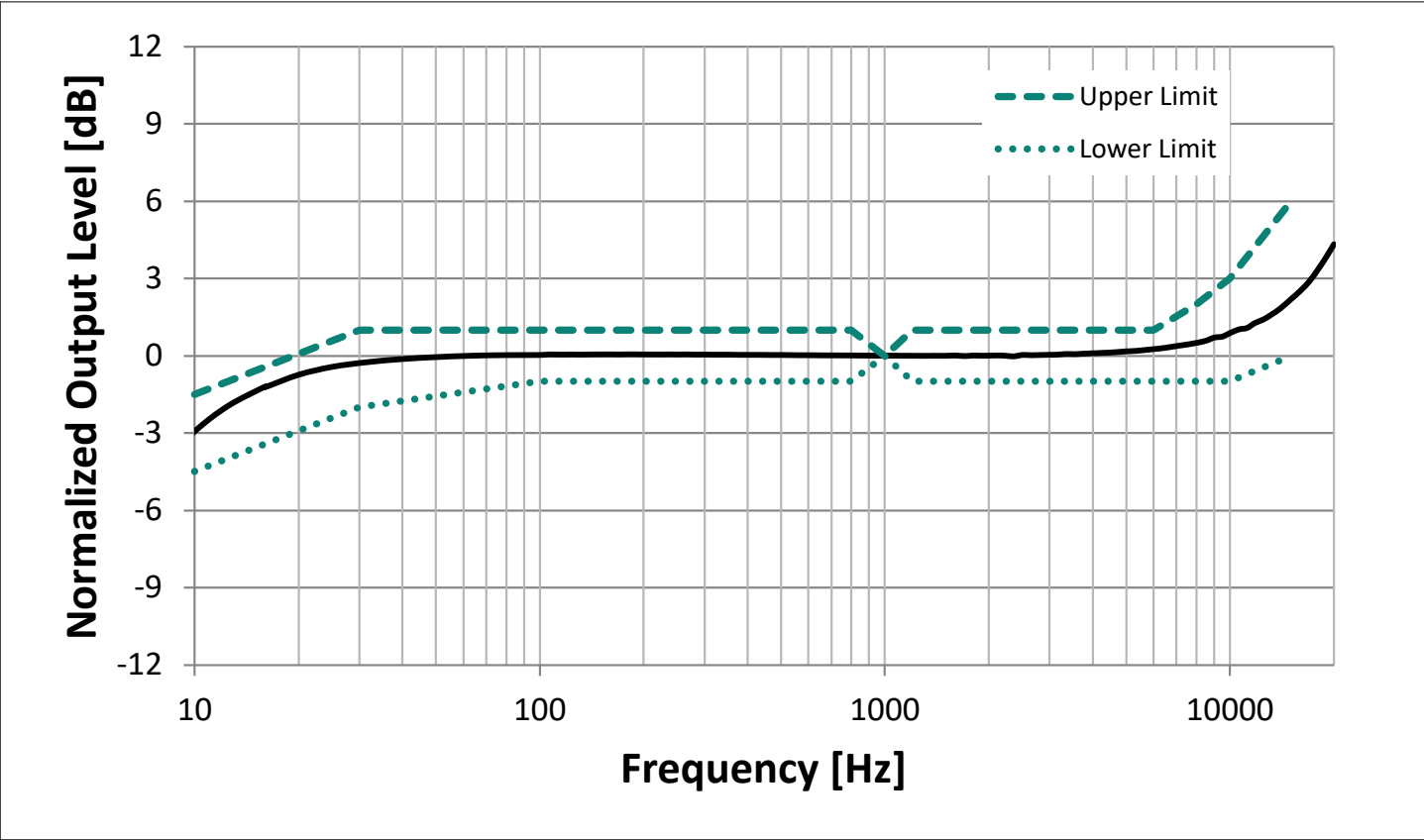


Figure 10 Free field frequency response

Table 3 Free field frequency response, normalized to 1kHz sensitivity value

Frequency [Hz]	Upper limit [dB]	Lower limit [dB]
10	-1.5	-4.5
30	1	-2
100	1	-1
800	1	-1
1000	0	0
1200	1	-1
6000	1	-1
8000	2	-1
10000	3	-1
15000	6	0

5 Electrical characteristics and parameters

5.1 Absolute maximum ratings

Table 4 Absolute maximum ratings

Stresses exceeding the listed maximum ratings may affect device reliability or cause permanent device damage. Functional device operation at these conditions is not guaranteed. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Maximum ratings are absolute ratings; exceeding only one of these values may cause irreversible damage to the integrated circuit.

Parameter	Symbol	Values		Unit	Note/Test Condition
		Min.	Max.		
Voltage on any Pin	V_{Maximum}		3.6	V	
Storage Temperature	T_S	-40	125	°C	¹⁾
Operating Temperature	T_A	-40	85	°C	

5.2 Electrical parameters

Table 5 Electrical parameters and digital interface input

Test conditions (unless otherwise specified in the table): $V_{DD} = 1.8V$, $T_A = 25^\circ\text{C}$, 55% R.H.

Parameter		Symbol	Values			Unit	Note / Test Condition
			Min.	Typ.	Max.		
Supply Voltage		V _{DD}	1.6	1.8	3.465	V	2)
Clock Frequency Range	Standby Mode	f _{clock}			330	kHz	3)
	Low Power Mode		370	406	440		
			480	600	650		
			720	768	840		
			930	1000	1220		
	Normal Mode	1.34	1.536	1.72	MHz		
		1.91	2.0	2.09			
		2.31	2.4	2.57			
		2.84	3.072	3.44			
3.81		4.0	4.18				
V _{DD} Ramp-up Time				50	ms	Time until V _{DD} ≥ V _{DD_min}	
Input Logic Low Level		V _{IL}		0.3xV _{DD}	V		
Input Logic High Level		V _{IH}	0.7xV _{DD}		V		
Clock Rise/Fall Time		T _{CR} /T _{CF}		13	ns	10% to 90% of V _{DD}	

(table continues...)

¹⁾ [Storage of Products Supplied by Infineon Technologies](#)

²⁾ A 1 μF bypass capacitor shall be placed close to the microphone V_{DD} pad to ensure best SNR performance.

³⁾ Data pad is high impedance in standby mode.

⁴⁾ The clock frequencies between the switching thresholds of different modes cannot be used.

Table 5 (continued) Electrical parameters and digital interface input

Test conditions (unless otherwise specified in the table): $V_{DD} = 1.8V$, $T_A = 25^{\circ}C$, 55% R.H.

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Clock Duty Cycle		45		55	%	
Clock input capacitance	C_{in}		20		pF	
Data output load	C_{load}			100	pF	

5.3 Electrical characteristics

Table 6 General electrical characteristics

 Test conditions (unless otherwise specified in the table): $V_{DD} = 1.8V$, $T_A = 25^\circ C$, 55% R.H.

Parameter		Symbol	Values			Unit	Note / Test Condition
			Min.	Typ.	Max.		
Current Consumption	Clock Off Mode	$I_{\text{clock_off}}$		1	5	μA	CLOCK pulled low
	Standby Mode	I_{standby}		95			No load on DATA
	$F_{\text{clock}} = 768\text{kHz}$	I_{DD}		170	200		<5pF load on DATA
	$F_{\text{clock}} = 1.536\text{MHz}$			420			
	$F_{\text{clock}} = 2.4\text{MHz}$			490			
	$F_{\text{clock}} = 3.072\text{MHz}$			540	640		
Short Circuit Current			1		20	mA	Grounded DATA pin
Start up Time	After powered down, $F_{\text{clock}} \geq 768\text{kHz}$ ⁵⁾				25	ms	Time after stable clock until sensitivity accuracy $\pm 1.0\text{dB}$
	After powered down, $F_{\text{clock}} < 768\text{kHz}$ ⁶⁾				45	ms	Time after stable clock until sensitivity accuracy $\pm 1.0\text{dB}$
Power Supply Rejection		PSR_{1k_NM}		-88		dBFS	100mV _{pp} sine wave on V_{DD} swept from 200Hz to 20kHz.
		PSR_{217_NM}		-91		dBFS(A)	100mV _{pp} , 217Hz square wave on V_{DD} . A-weighted.
Output Logic Low Level		V_{OL}			$0.2 \times V_{DD}$	V	
Output Logic High Level		V_{OH}	$0.8 \times V_{DD}$				
Delay Time for DATA Driven		t_{DD}	60		100	ns	Delay time from CLOCK edge ($0.5 \times V_{DD}$) to DATA driven.
Delay Time for DATA High-Z ⁷⁾		t_{HZ}	5		30	ns	Delay time from CLOCK edge ($0.5 \times V_{DD}$) to DATA high impedance state
Delay Time for DATA Valid ⁸⁾		t_{DV}			140	ns	Delay time from CLOCK edge ($0.5 \times V_{DD}$) to DATA valid ($< 0.3 \times V_{DD}$ or $> 0.7 \times V_{DD}$)
Power-on behaviour		Idle tone is output over PDM within 3ms of applying V_{DD} and f_{clock} , remains until a valid microphone signal is available. Idle tone consists of alternating 1s and 0s, representing a zero input signal.					

⁵⁾ Mode switch time to any specified frequency $\geq 768\text{kHz}$, from any specified frequency $\geq 768\text{kHz}$ or Off. V_{DD} is always present during mode switching.

⁶⁾ Mode switch time to any specified frequency $< 768\text{kHz}$, from any specified frequency or Off. V_{DD} is always present during mode switching.

⁷⁾ t_{hold} is dependent on C_{load}

⁸⁾ Load on data: $C_{\text{load}} = 100\text{pF}$, $R_{\text{load}} = 100\text{k}\Omega$

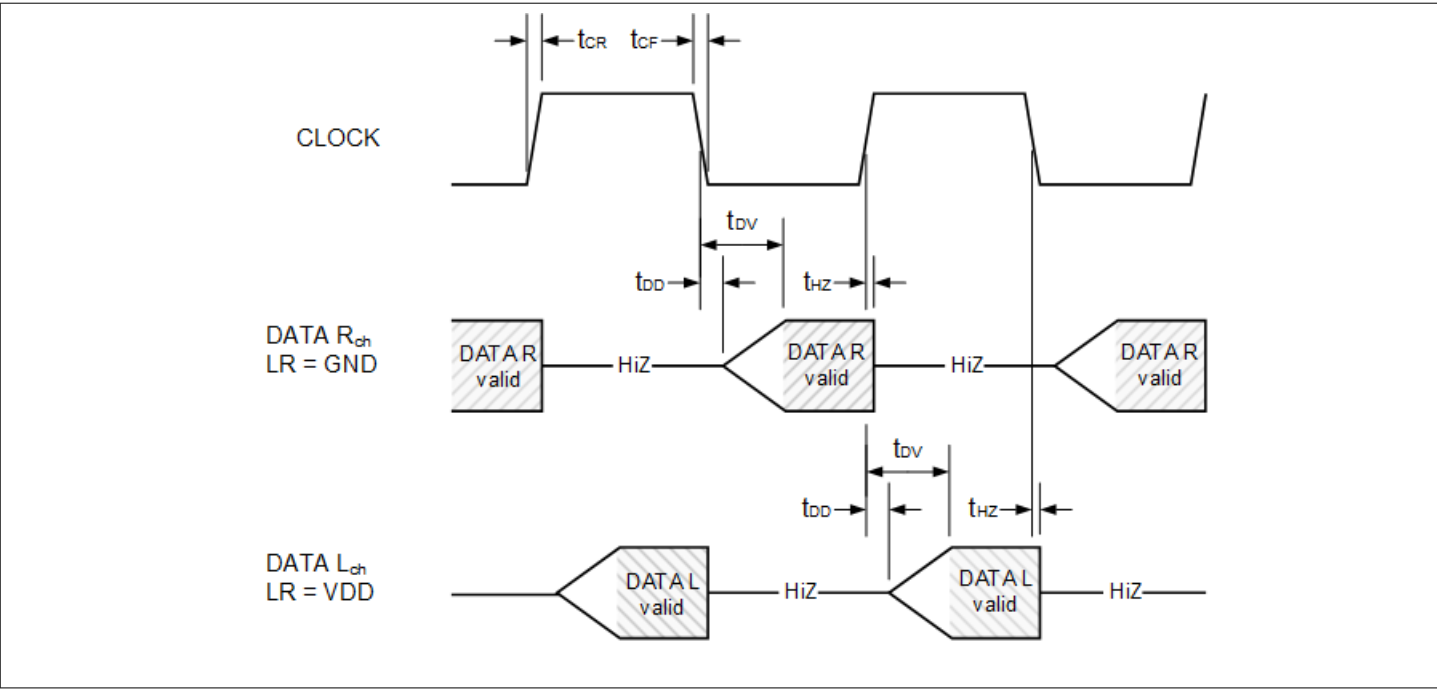


Figure 11 Timing diagram

5.4 Audio DC offset

The DC output level encoded in the DC bit stream is determined by the L/R state on startup. In each case the DC output level is stable over time and does not vary with input signal level.

Table 7 DC output level using L/R pin

LR state	DC output level (typical)	Unit
LR = GND	-90	dBFS
LR = VDD	-30	dBFS

5.5 Stereo PDM configuration

The IM67D128BV01 is designed to function in circuits with one or two microphones on the PDM bus. When two microphones are connected, data is transmitted alternately according to the L/R pin status of each microphone. When two microphones are connected to a shared PDM bus, the power modes of both microphones will be the same as both are controlled by the same PDM clock. The performance is unchanged relative to a single microphone per bus configuration.

Table 8 PDM channel configuration using L/R pin.

Channel	Data driven	Data high-Z	L/R connection
DATA1	Falling clock edge	Rising clock edge	GND
DATA2	Rising clock edge	Falling clock edge	V _{DD}

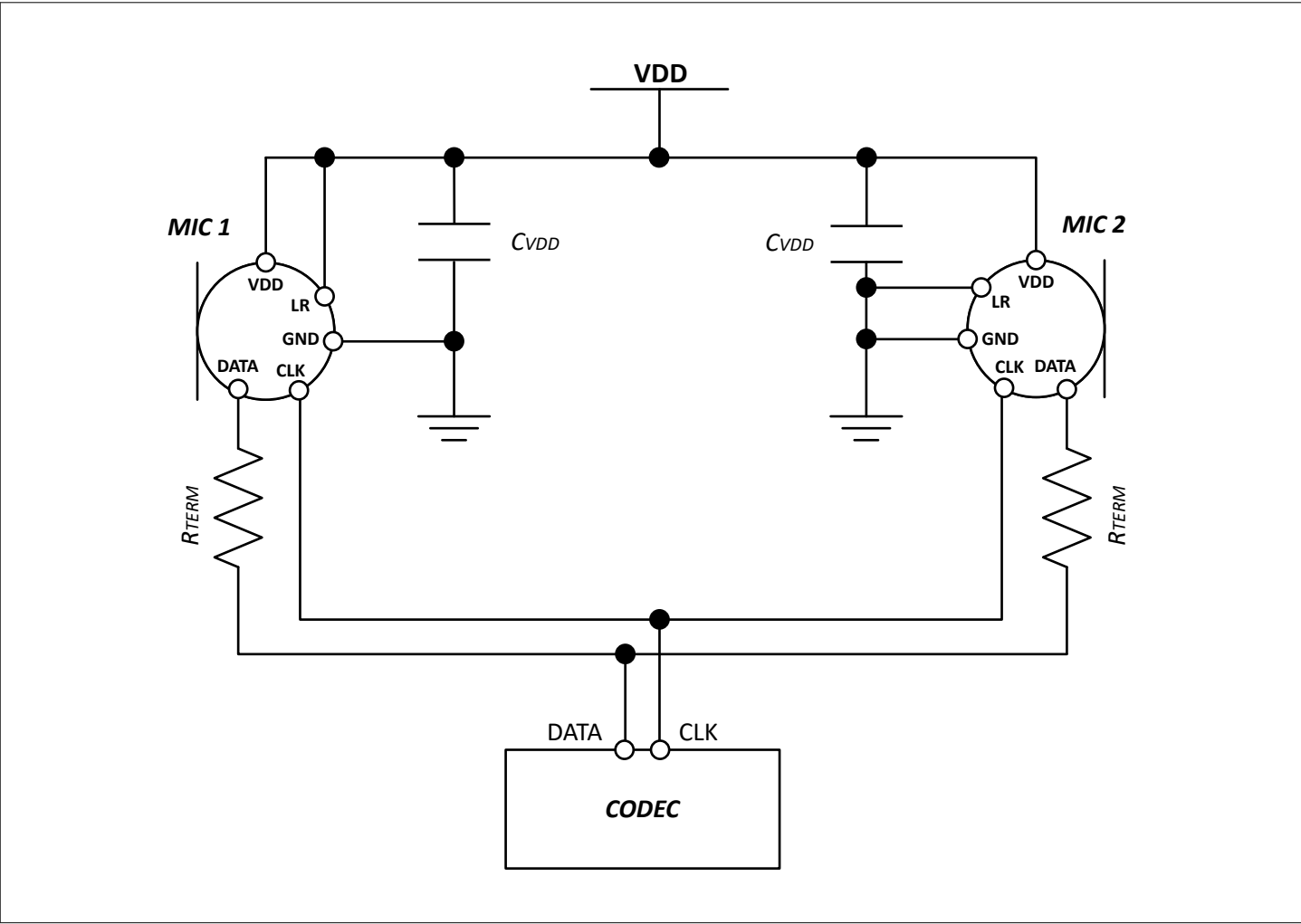


Figure 12 Typical stereo mode configuration

Note: For best performance it is strongly recommended to place a 1µF ($C_{VDD_typical}$) capacitor between V_{DD} and ground. The capacitor should be placed as close to V_{DD} as possible. A termination resistor (R_{TERM}) of about 100Ω may be added to reduce the ringing and overshoot on the output signal.

6 Package information

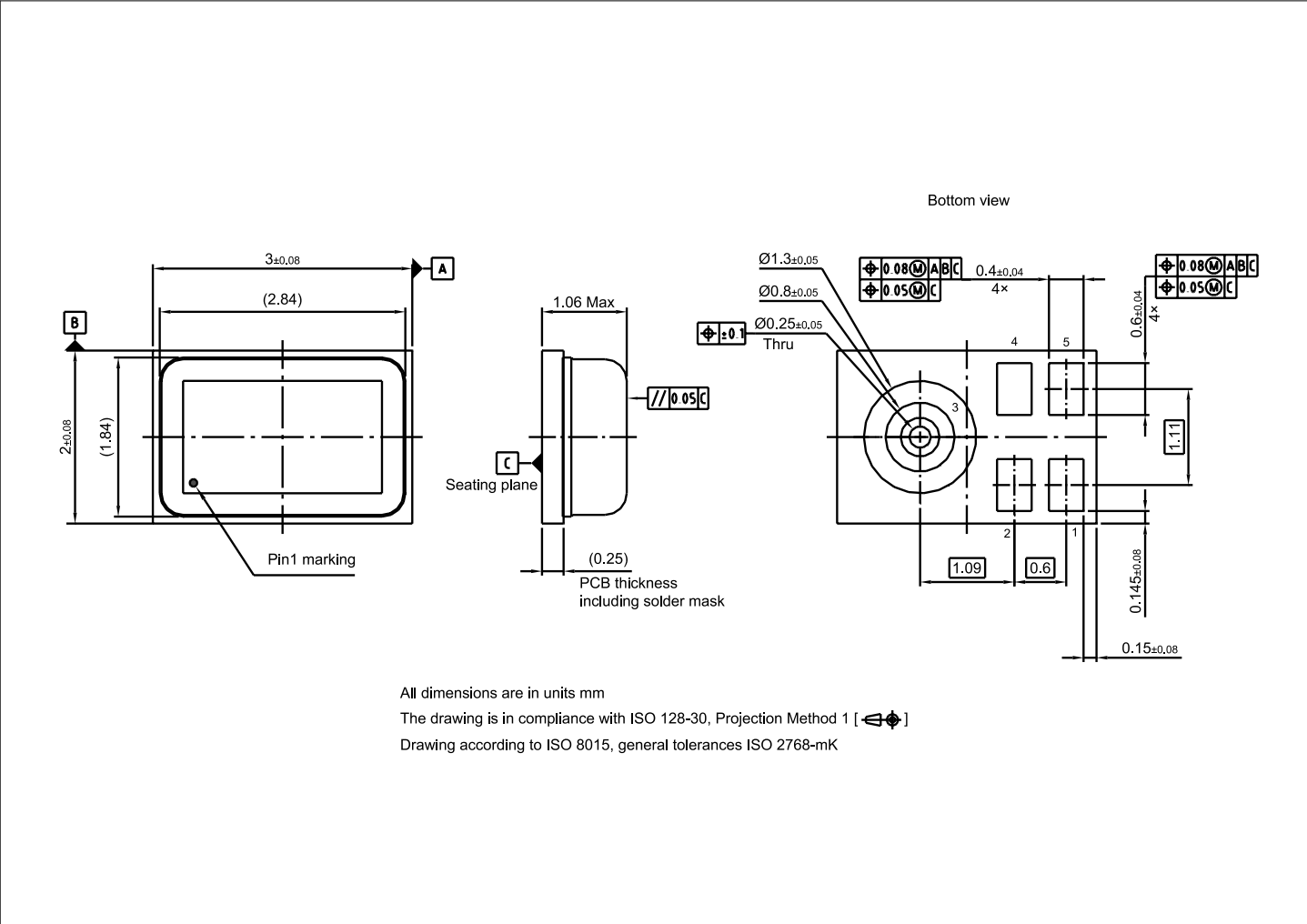


Figure 13 IM67D128BV01 package drawing

Table 9 IM67D128BV01 pin configuration

Pin Number	Name	Description
1	DATA	PDM data output
2	LR select	PDM left/right select
3	GND	Ground
4	CLOCK	PDM clock input
5	V _{DD}	Power supply

7 Packing information

For shipping and assembly the Infineon microphones are packed in product specific tape-and-reel carriers. A detailed drawing of the carrier can be seen in

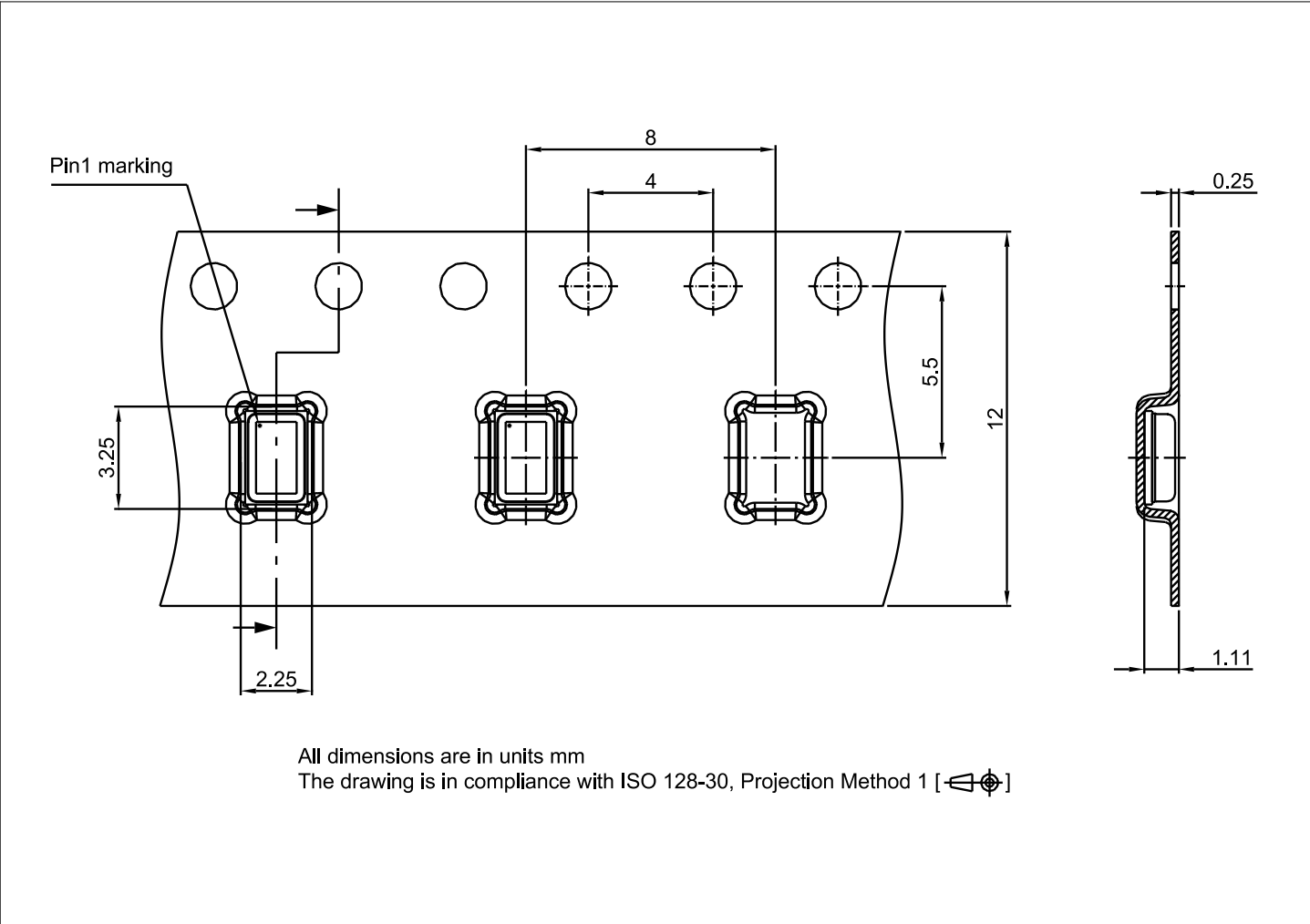


Figure 14 IM67D128BV01 tape and reel packing information

Table 10 IM67D128BV01 packaging information

Product	Type code	Reel diameter	Quantity per reel
IM67D128BV01	I67D30	13"	5000

8 Footprint and stencil recommendation

The acoustic port hole diameter in the PCB should be larger than the acoustic port hole diameter of the MEMS microphone to ensure optimal performance. A PCB sound port size of diameter 0.6 mm is recommended.

The board pad and stencil aperture recommendations shown below are based on Non-Solder Mask Defined (NSMD) pads. The specific design rules of the board manufacturer should be considered for individual design optimizations or adaptations.

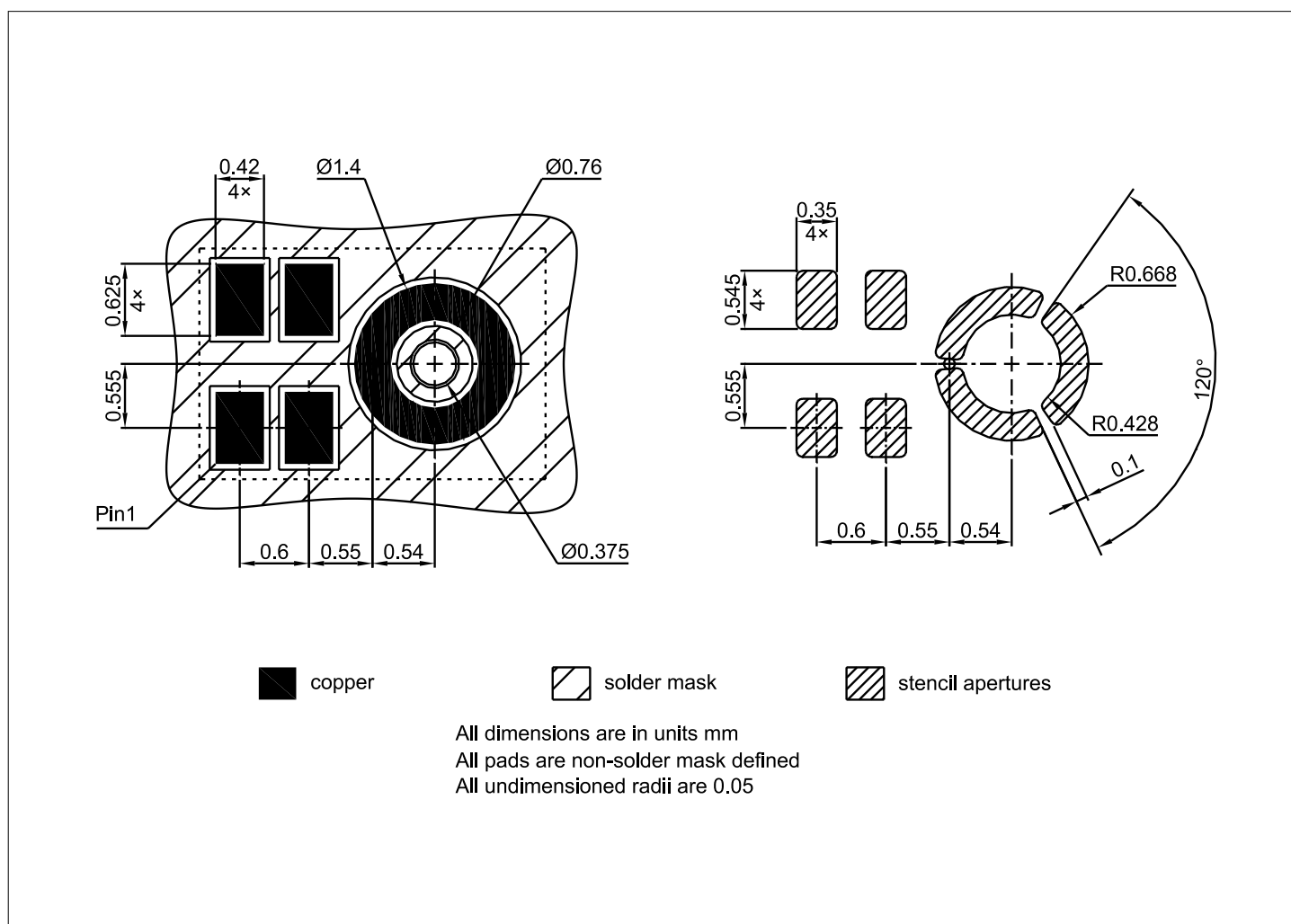


Figure 15 Footprint and stencil recommendation

9 Reflow soldering and board assembly

Infineon MEMS microphones are qualified in accordance with the IPC/JEDEC J-STD-020D-01. The moisture sensitivity level of MEMS microphones is rated as MSL1. For PCB assembly of the MEMS microphone the widely used reflow soldering using a forced convection oven is recommended.

The soldering profile should be in accordance with the recommendations of the solder paste manufacturer to reach an optimal solder joint quality. The reflow profile shown in [Figure 16](#) is recommended for board manufacturing with Infineon MEMS microphones.

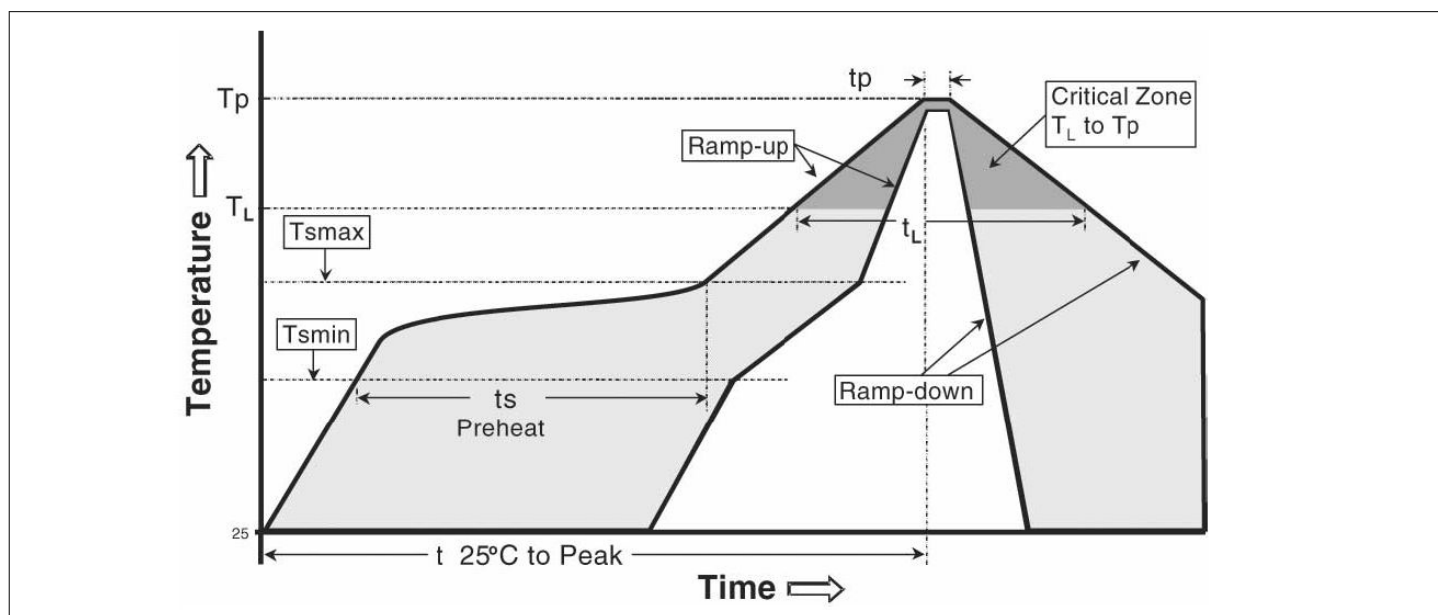


Figure 16 Recommended reflow profile

Table 11 Reflow profile limits

Profile feature	Pb-Free assembly	Sn-Pb Eutectic assembly
Temperature Min (T_{smin})	150 °C	100 °C
Temperature Max (T_{smax})	200 °C	150 °C
Time (T_{smin} to T_{smax}) (t_s)	60-120 seconds	60-120 seconds
Ramp-up rate (T_L to T_P)	3 °C/second max.	3 °C/second max.
Liquidous temperature (T_L)	217 °C	183 °C
Time (t_L) maintained above T_L	60-150 seconds	60-150 seconds
Peak Temperature (T_P)	260°C +0°C/-5°C	235°C +0°C/-5°C
Time within 5°C of actual peak temperature (t_p) ⁹⁾	20-40 seconds	10-30 seconds
Ramp-down rate	6 °C/second max.	6 °C/second max.
Time 25°C to peak temperature	8 minutes max.	6 minutes max.

Note: For further information please consult the 'General recommendation for assembly of Infineon packages' document which is available on the [Infineon Technologies web page](#)

⁹ Tolerance for peak profile temperature (T_P) is defined as a supplier minimum and a user maximum

The MEMS microphones can be handled using industry standard pick and place equipment. Care should be taken to avoid damage to the microphone structure as follows:

- Do not pick the microphone with vacuum tools which make contact with the microphone acoustic port hole.
- The microphone acoustic port hole should not be exposed to vacuum, this can destroy or damage the MEMS.
- Do not blow air into the microphone acoustic port hole. If an air blow cleaning process is used, the port hole must be sealed to prevent particle contamination.
- It is recommended to perform the PCB assembly in a clean room environment in order to avoid microphone contamination.
- Air blow and ultrasonic cleaning procedures shall not be applied to MEMS Microphones. A no-clean paste is recommended for the assembly to avoid subsequent cleaning steps. The microphone MEMS can be severely damaged by cleaning substances.
- To prevent the blocking or partial blocking of the sound port during PCB assembly, it is recommended to cover the sound port with protective tape during PCB sawing or system assembly.
- Do not use excessive force to place the microphone on the PCB. The use of industry standard pick and place tools is recommended in order to limit the mechanical force exerted on the package.

10 Reliability specifications

The microphone sensitivity after stress must deviate by no more than 3dB from the initial value.

Table 12 Reliability specification

Test	Abbreviation	Test Condition	Standard
Low Temperature Operating Life	LTOL	$T_a = -40^{\circ}\text{C}$, VDD=3.6V, 1000 hours	JESD22-A108
Low Temperature Storage Life	LTSL	$T_a = -40^{\circ}\text{C}$, 1000 hours	JESD22-A119
High Temperature Operation Life	HTOL	$T_a = +125^{\circ}\text{C}$, VDD=3.6V, 1000 hours	JESD22-A108
High Temperature Storage Life	HTSL	$T_a = +125^{\circ}\text{C}$, 1000 hours	JESD22-A103
Temperature Cycling	PC + TC	Pre conditioning MSL-1	JESD22-A113
		1000 cycles, -40°C to $+125^{\circ}\text{C}$, 30 minutes per cycle	JESD22-A104
Temperature Humidity Bias	PC + THB	Pre conditioning MSL-1	JESD22-A113
		$T_a = +85^{\circ}\text{C}$, R.H = 85%, VDD=3.6V, 1000 hours	JESD22-A101
Vibration Test	VVF	20Hz to 2000Hz with a peak acceleration of 20g in X, Y, and Z for 4 minutes each, total 4 -cycles	IEC 60068-2-6
Mechanical Shock	MS	10000g/0.2msec direction $\pm x, y, z$, 5 shocks in each direction, 5 shocks in total	IEC 60068-2-27
Reflow Solder ¹⁰⁾	RS	3 reflow cycles, peak temperature = $+260^{\circ}\text{C}$	IPC-JEDEC J-STD-020D-01
Electrostatic Discharge -System Level Test	ESD - SLT	3 discharges of $\pm 8\text{kV}$ direct contact to lid while V_{dd} is supplied according to the operational modes; (V_{dd} ground is separated from earth ground)	IEC-61000-4-2
Electrostatic Discharge - Human Body Model	ESD - HBM	1 pulse of $\pm 2\text{kV}$ between all I/O pin combinations	JEDEC-JS001
Electrostatic Discharge - Charged Device Model	ESD - CDM	3 discharges of $\pm 500\text{V}$ direct contact to I/O pins.	JEDEC JS-002
Latch Up	LU	Trigger current from $\pm 100\text{mA}$	JESD78E

¹⁰⁾ The microphone sensitivity must deviate by no more than 1dB from the initial value after 3 reflow cycles.

10.1 Environmental robustness

Infineon's latest Single Backplate MEMS technology delivers high ingress protection (IP57) on microphone level. The MEMS is designed to reduce the risk of mechanical blockage or electrical fail caused by water or dust.

Table 13 Environmental robustness

Test Standard	Test Condition
IP5x dust resistance ¹¹⁾	Arizona dust A4 coarse, vertical orientation, sound hole upwards, 10 cycles (15 minutes sedimentation, 6 sec blowing)
IPx7 water immersion ¹²⁾	Temporary immersion of 1 meters for 30 minutes. Microphone tested 6 hours after removal

¹¹ The number "5" stands for the dust ingress rating or the capacity to withstand the effects of fine, abrasive dust particles.

¹² The "7" specifies the higher water immersion rating.



Revision history

Document version	Date of release	Description of changes
V1.0	2025-07-23	Datasheet

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